ALPHA & OMEGA SEMICONDUCTOR

# AOD600A60/AOI600A60

## 600V, aMOS5™ N-Channel Power Transistor

### General Description

- Proprietary αMOS5™ technology
- Low $R_{DS(ON)}$
- Optimized switching parameters for better EMI performance
- Enhanced body diode for robustness and fast reverse recovery

### Applications

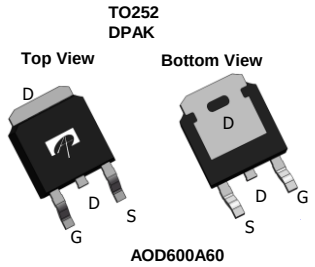
- SMPS with PFC, Flyback and LLC topologies
- Silver ATX,adapter,TV,lighting,Server power

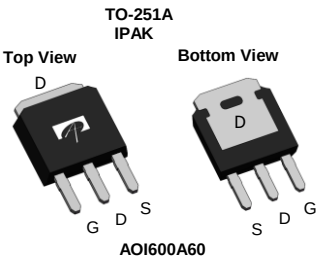
### Product Summary

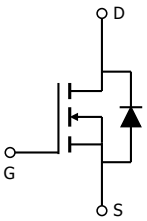
| | |
|---|---|
| $V_{DS}$ @ $T_{j,max}$ | 700V |
| $I_{DM}$ | 32A |
| $R_{DS(ON),max}$ | < 0.6Ω |
| $Q_{g,typ}$ | 11.5nC |
| $E_{oss}$ @ 400V | 1.8μJ |

100% UIS Tested
100% $R_g$ Tested

Green Product




| Orderable Part Number | Package Type | Form | Minimum Order Quantity |
|---|---|---|---|
| AOD600A60 | TO252 | Tape & Reel | 2500 |
| AOI600A60 | TO251A | Tube | 3500 |

**Absolute Maximum Ratings $T_A$=25°C unless otherwise noted**

| Parameter | | Symbol | Maximum | Units |
|---|---|---|---|---|
| Drain-Source Voltage | | $V_{DS}$ | 600 | V |
| Gate-Source Voltage | | $V_{GS}$ | ±20 | V |
| Gate-Source Voltage (dynamic) AC( f>1Hz) | | $V_{GS}$ | ±30 | V |
| Continuous Drain Current | $T_C$=25°C | $I_D$ | 8 | A |
| | $T_C$=100°C | | 5 | |
| Pulsed Drain Current [C] | | $I_{DM}$ | 32 | |
| Avalanche Current [C] L=1mH | | $I_{AR}$ | 1.6 | A |
| Repetitive avalanche energy [C] | | $E_{AR}$ | 1.3 | mJ |
| Single pulsed avalanche energy [H] | | $E_{AS}$ | 19 | mJ |
| MOSFET dv/dt ruggedness | | dv/dt | 100 | V/ns |
| Peak diode recovery dv/dt | | | 20 | |
| Power Dissipation [B] | $T_C$=25°C | $P_D$ | 96 | W |
| | Derate above 25°C | | 0.8 | W/°C |
| Junction and Storage Temperature Range | | $T_J$, $T_{STG}$ | -55 to 150 | °C |
| Maximum lead temperature for soldering purpose, 1/8" from case for 5 seconds | | $T_L$ | 300 | °C |

**Thermal Characteristics**

| Parameter | Symbol | Typical | Maximum | Units |
|---|---|---|---|---|
| Maximum Junction-to-Ambient [A,D] | $R_{\theta JA}$ | 45 | 55 | °C/W |
| Maximum Case-to-sink [A] | $R_{\theta CS}$ | - | 0.5 | °C/W |
| Maximum Junction-to-Case [D,F] | $R_{\theta JC}$ | 1 | 1.3 | °C/W |

**Electrical Characteristics ($T_J$=25°C unless otherwise noted)**

| Symbol | Parameter | Conditions | Min | Typ | Max | Units |
|---|---|---|---|---|---|---|
| **STATIC PARAMETERS** | | | | | | |
| $BV_{DSS}$ | Drain-Source Breakdown Voltage | $I_D$=250µA, $V_{GS}$=0V, $T_J$=25°C | 600 | | | V |
| | | $I_D$=250µA, $V_{GS}$=0V, $T_J$=150°C | | 700 | | |
| $BV_{DSS}$ /ΔTJ | Breakdown Voltage Temperature Coefficient | $I_D$=250µA, $V_{GS}$=0V | | 0.59 | | V/ °C |
| $I_{DSS}$ | Zero Gate Voltage Drain Current | $V_{DS}$=600V, $V_{GS}$=0V | | | 1 | µA |
| | | $V_{DS}$=480V, $T_J$=125°C | | | 10 | |
| $I_{GSS}$ | Gate-Body leakage current | $V_{DS}$=0V, $V_{GS}$=±20V | | | ±100 | nA |
| $V_{GS(th)}$ | Gate Threshold Voltage | $V_{DS}$=5V, $I_D$=250µA | 2.9 | 3.5 | 4.1 | V |
| $R_{DS(ON)}$ | Static Drain-Source On-Resistance | $V_{GS}$=10V, $I_D$=2.1A | | 0.53 | 0.6 | Ω |
| $g_{FS}$ | Forward Transconductance | $V_{DS}$=10V, $I_D$=2.1A | | 4.2 | | S |
| $V_{SD}$ | Diode Forward Voltage | $I_S$=2.1A,$V_{GS}$=0V | | 0.8 | 1.2 | V |
| $I_S$ | Maximum Body-Diode Continuous Current | | | | 8 | A |
| $I_{SM}$ | Maximum Body-Diode Pulsed Current [C] | | | | 32 | A |
| **DYNAMIC PARAMETERS** | | | | | | |
| $C_{iss}$ | Input Capacitance | $V_{GS}$=0V, $V_{DS}$=100V, f=1MHz | | 608 | | pF |
| $C_{oss}$ | Output Capacitance | | | 19 | | pF |
| $C_{o(er)}$ | Effective output capacitance, energy related [I] | $V_{GS}$=0V, $V_{DS}$=0 to 480V, f=1MHz | | 21 | | pF |
| $C_{o(tr)}$ | Effective output capacitance, time related [J] | | | 76 | | pF |
| $C_{rss}$ | Reverse Transfer Capacitance | $V_{GS}$=0V, $V_{DS}$=100V, f=1MHz | | 1.3 | | pF |
| $R_g$ | Gate resistance | f=1MHz | | 4.6 | | Ω |
| **SWITCHING PARAMETERS** | | | | | | |
| $Q_g$ | Total Gate Charge | $V_{GS}$=10V, $V_{DS}$=480V, $I_D$=2.1A | | 11.5 | | nC |
| $Q_{gs}$ | Gate Source Charge | | | 4.2 | | nC |
| $Q_{gd}$ | Gate Drain Charge | | | 2.8 | | nC |
| $T_{d(on)}$ | Turn-On DelayTime | $V_{GS}$=10V, $V_{DS}$=400V, $I_D$=2.1A, $R_G$=5Ω | | 18 | | ns |
| $T_r$ | Turn-On Rise Time | | | 5.5 | | ns |
| $T_{d(off)}$ | Turn-Off DelayTime | | | 36 | | ns |
| $T_f$ | Turn-Off Fall Time | | | 16 | | ns |
| $T_{rr}$ | Body Diode Reverse Recovery Time | $I_F$=2.1A, dI/dt=100A/µs, $V_{DS}$=400V | | 159 | | ns |
| $I_{rm}$ | Peak Reverse Recovery Current | | | 13 | | A |
| $Q_{rr}$ | Body Diode Reverse Recovery Charge | | | 1.2 | | µC |

A. The value of $R_{qJA}$ is measured with the device in a still air environment with $T_A$ =25° C.
B. The power dissipation $P_D$ is based on $T_{J(MAX)}$=150° C in a TO252 package, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heatsinking is used.
C. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$=150° C.
D. The $R_{\theta JA}$ is the sum of the thermal impedance from junction to case $R_{qJC}$ and case to ambient.
E. The static characteristics in Figures 1 to 6 are obtained using <300µs pulses, duty cycle 0.5% max.
F. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of $T_{J(MAX)}$=150° C.
G.These tests are performed with the device mounted on 1 $in^2$ FR-4 board with 2oz. Copper, in a still air environment with $T_A$=25° C.
H. L=60mH, $I_{AS}$=0.8A, $R_G$=25Ω, Starting $T_J$=25° C.
I. $C_{o(er)}$ is a fixed capacitance that gives the same stored energy as $C_{oss}$ while $V_{DS}$ is rising from 0 to 80% $V_{(BR)DSS}$.
J. $C_{o(tr)}$ is a fixed capacitance that gives the same charging time as $C_{oss}$ while $V_{DS}$ is rising from 0 to 80% $V_{(BR)DSS}$.

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## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

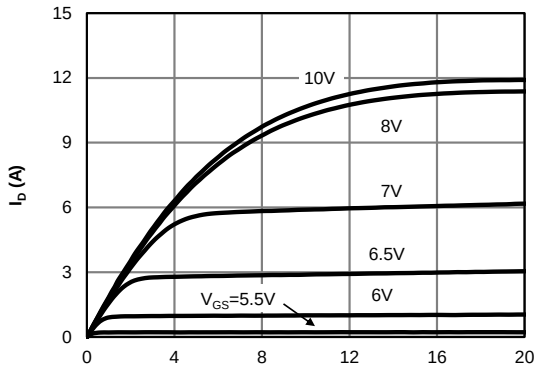



**Figure 1: On-Region Characteristics**

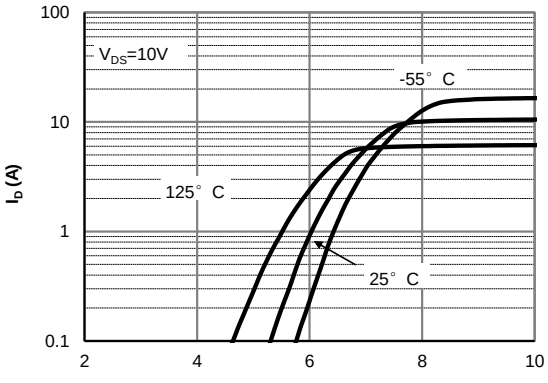



**Figure 2: Transfer Characteristics**

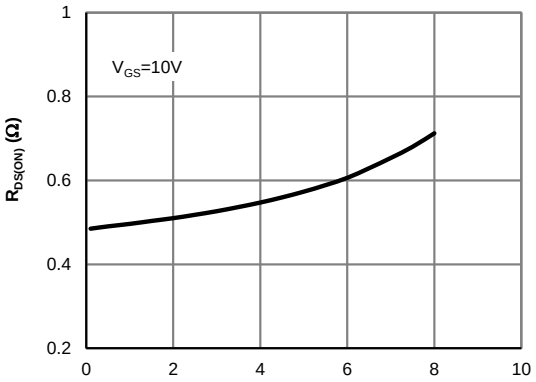



**Figure 3: On-Resistance vs. Drain Current and Gate Voltage**

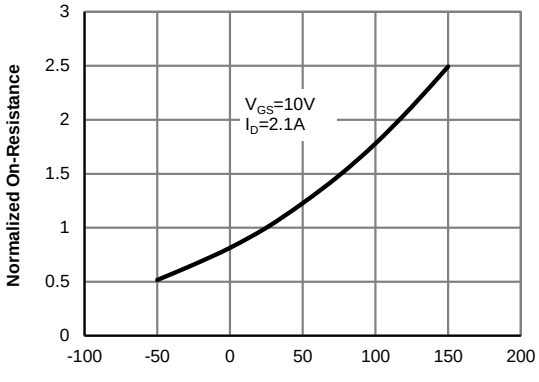



**Figure 4: On-Resistance vs. Junction Temperature**

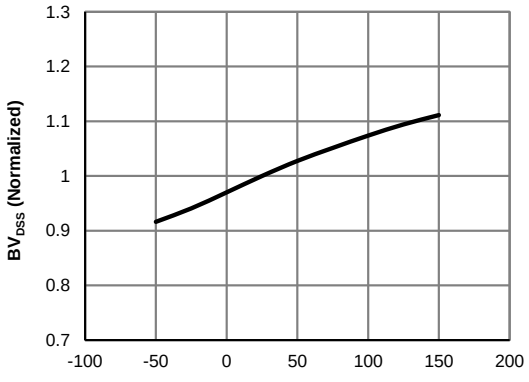



**Figure 5: Break Down vs. Junction Temparature**

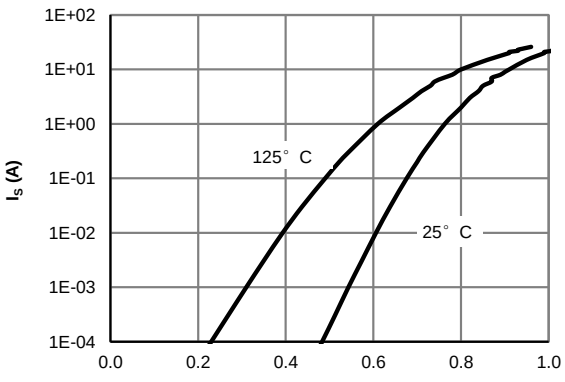



**Figure 6: Body-Diode Characteristics**

## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

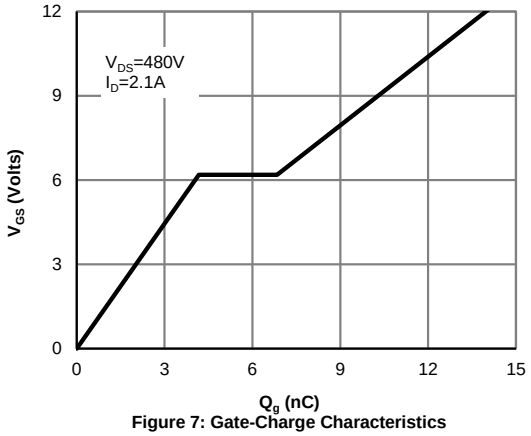



**Figure 7: Gate-Charge Characteristics**

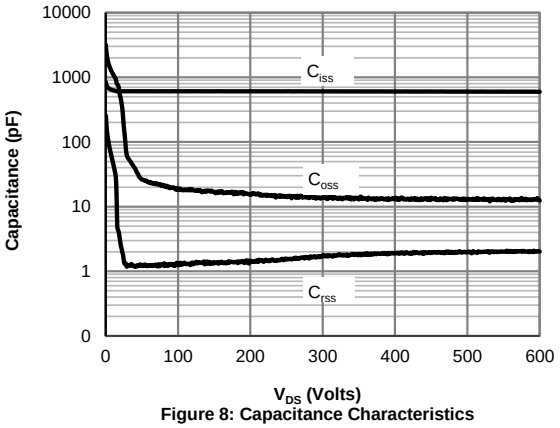



**Figure 8: Capacitance Characteristics**

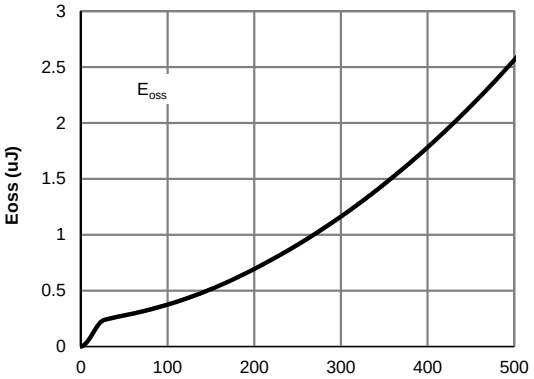



**Figure 9: Coss stored Energy**

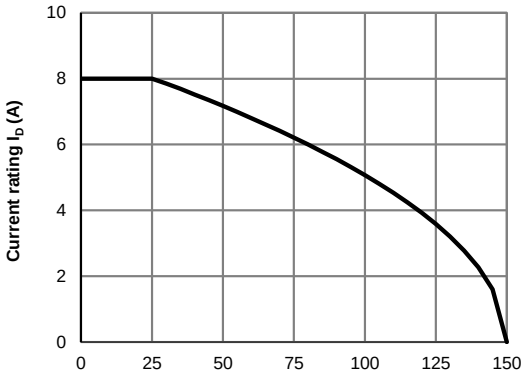



**Figure 10: Current De-rating (Note F)**

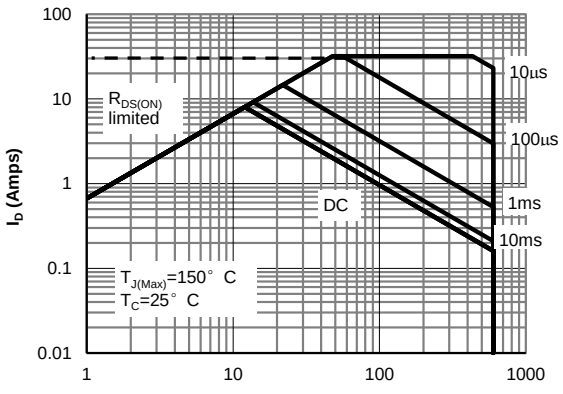



**Figure 11: Maximum Forward Biased Safe Operating Area (Note F)**

## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

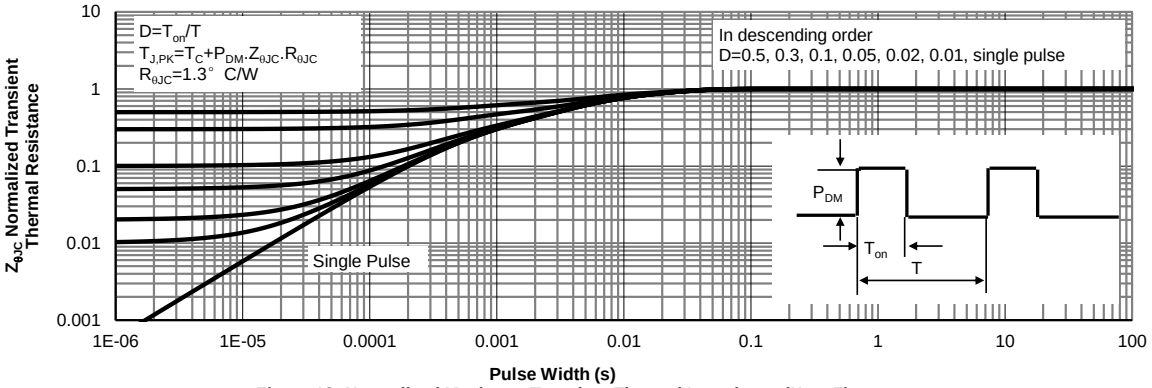
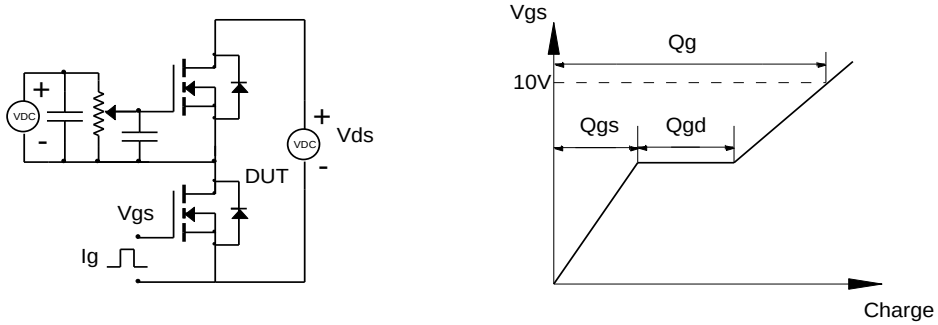
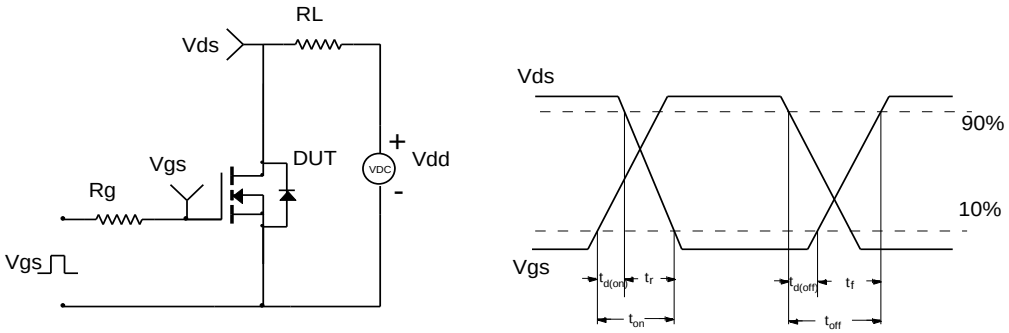



**Figure 12: Normalized Maximum Transient Thermal Impedance (Note F)**

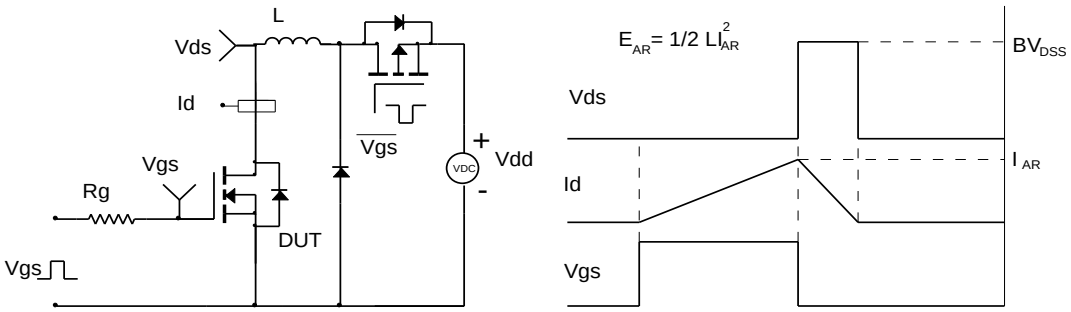
## Gate Charge Test Circuit & Waveform



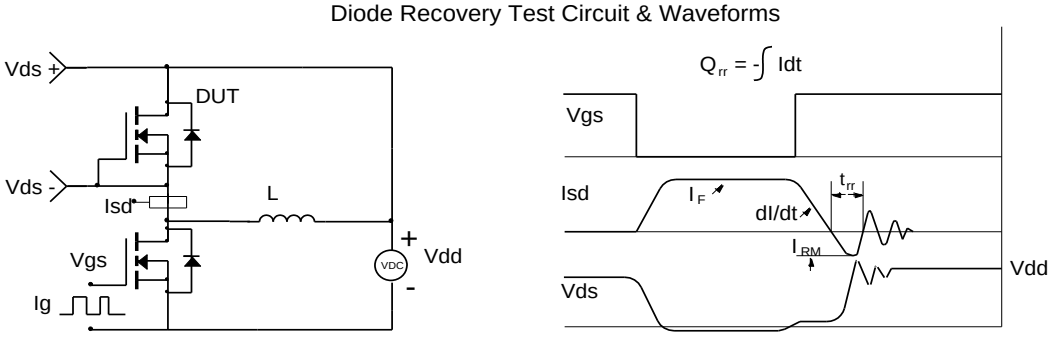

## Resistive Switching Test Circuit & Waveforms




## Unclamped Inductive Switching (UIS) Test Circuit & Waveforms




## Diode Recovery Test Circuit & Waveforms



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